

BAT54 / BAT54A / BAT54C / BAT54S

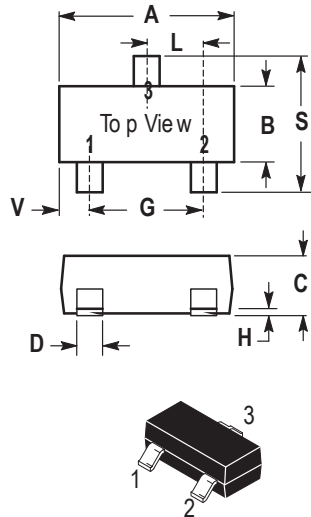
Surface Mount Schottky
Barrier Diode

Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection

Mechanical Data

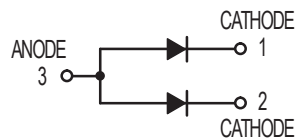
- Case: Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams Below
- Weight: 0.008 grams (approx.)
- Mounting Position: Any



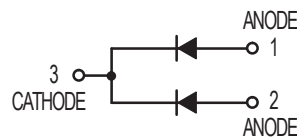
| SOT-23 | | |
|---------------------|-------|-------|
| Dim | Min | Max |
| A | 2.800 | 3.040 |
| B | 1.200 | 1.400 |
| C | 0.890 | 1.110 |
| D | 0.370 | 0.500 |
| G | 1.780 | 2.040 |
| H | 0.013 | 0.100 |
| J | 0.085 | 0.177 |
| K | 0.450 | 0.600 |
| L | 0.890 | 1.020 |
| S | 2.100 | 2.500 |
| V | 0.450 | 0.600 |
| All Dimension in mm | | |



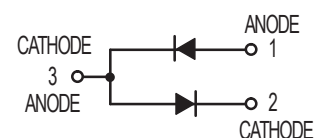
BAT54 Marking : LV3



BAT54A Marking : BG



BAT54C Marking : KV3



BAT54S Marking : LD3

MAXIMUM RATINGS (T_J = 125 °C unless otherwise noted)

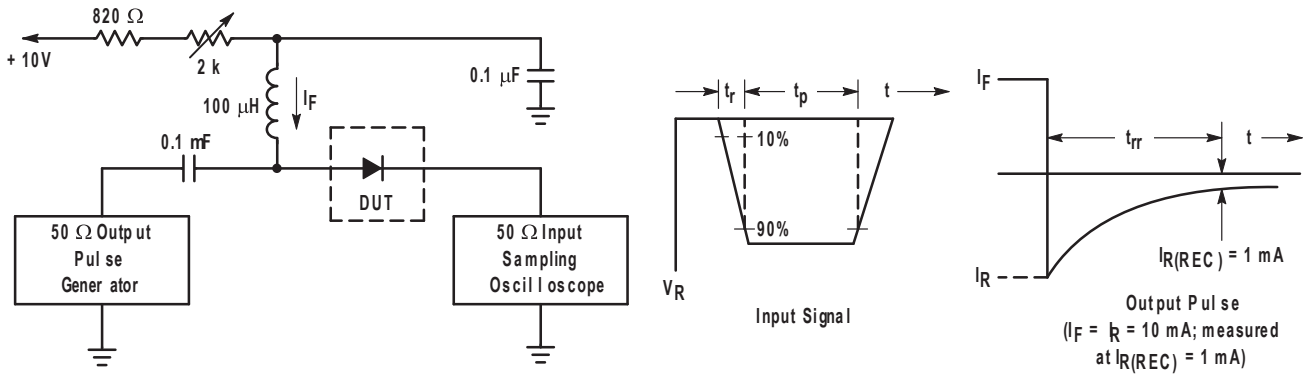
| Rating | Symbol | Value | Unit |
|---|------------------|-------------|-------------|
| Reverse Voltage | V _R | 30 | Volts |
| Forward Power Dissipation @ T _A = 25 °C Derate above 25 °C | P _F | 225 1.8 | mW mW/°C |
| Forward Current (DC) | I _F | 200 Max | mA |
| Junction Temperature | T _J | 125 Max | °C |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted) (EACH DIODE)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|--------------------|-----|------|------|-------|
| Reverse Breakdown Voltage (I _R = 10 mA) | V _{(BR)R} | 30 | — | — | Volts |
| Total Capacitance (V _R = 1.0 V, f = 1.0 MHz) | C _T | — | 7.6 | 10 | pF |
| Reverse Leakage (V _R = 25 V) | I _R | — | 0.5 | 2.0 | mAdc |
| Forward Voltage (I _F = 0.1 mAdc) | V _F | — | 0.22 | 0.24 | Vdc |
| Forward Voltage (I _F = 30 mAdc) | V _F | — | 0.41 | 0.5 | Vdc |
| Forward Voltage (I _F = 100 mAdc) | V _F | — | 0.52 | 1.0 | Vdc |
| Reverse Recovery Time (I _F = I _R = 10 mAdc, I _{R(REC)} = 1.0 mAdc) Figure 1 | t _{rr} | — | — | 5.0 | ns |
| Forward Voltage (I _F = 1.0 mAdc) | V _F | — | 0.29 | 0.32 | Vdc |
| Forward Voltage (I _F = 10 mAdc) | V _F | — | 0.35 | 0.40 | Vdc |
| Forward Current (DC) | I _F | — | — | 200 | mAdc |
| Repetitive Peak Forward Current | I _{FRM} | — | — | 300 | mAdc |
| Non repetitive Peak Forward Current (t < 1.0 s) | I _{FSM} | — | — | 600 | mAdc |

RATINGS AND CHARACTERISTIC CURVES BAT54 / BAT54A / BAT54C / BAT54S

Figure 1. Recovery Time Equivalent Test Circuit



- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10 mA.
3. $t_p \gg t_{rr}$

Figure 2. Forward Voltage

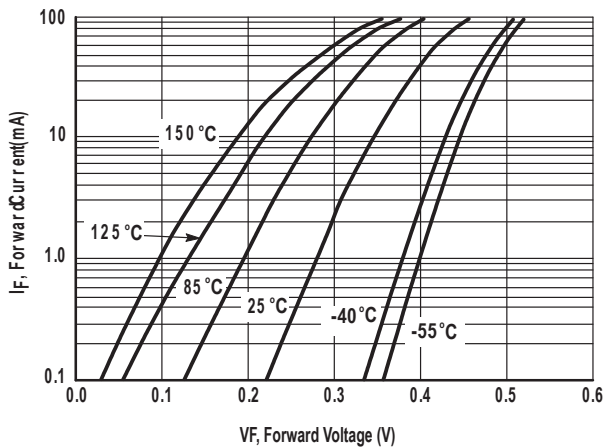


Figure 3. Leakage Current

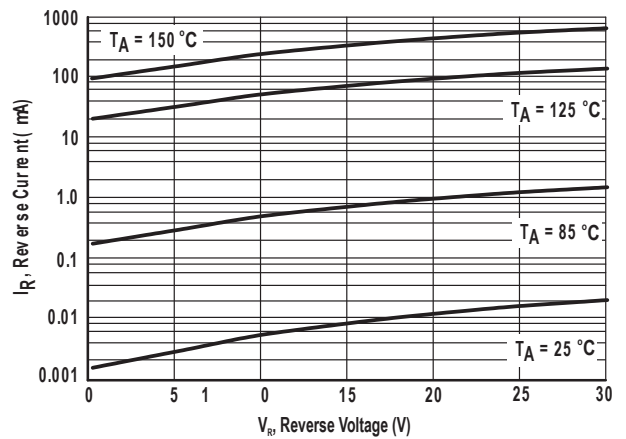


Figure 4. Total Capacitance

